

Self-sputtering during isotope collections

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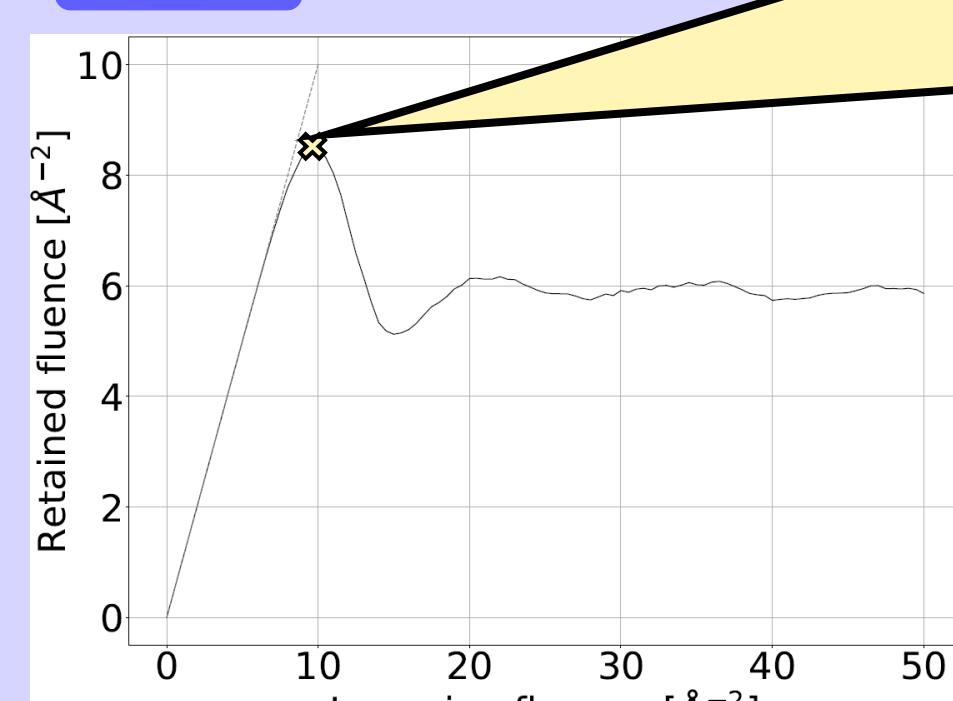
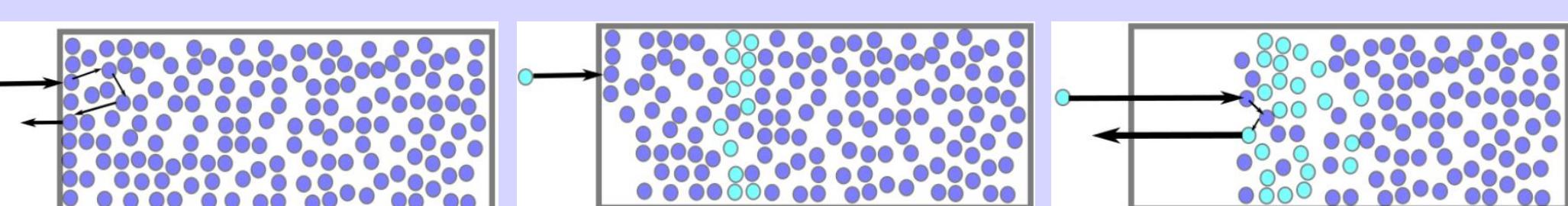
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Context

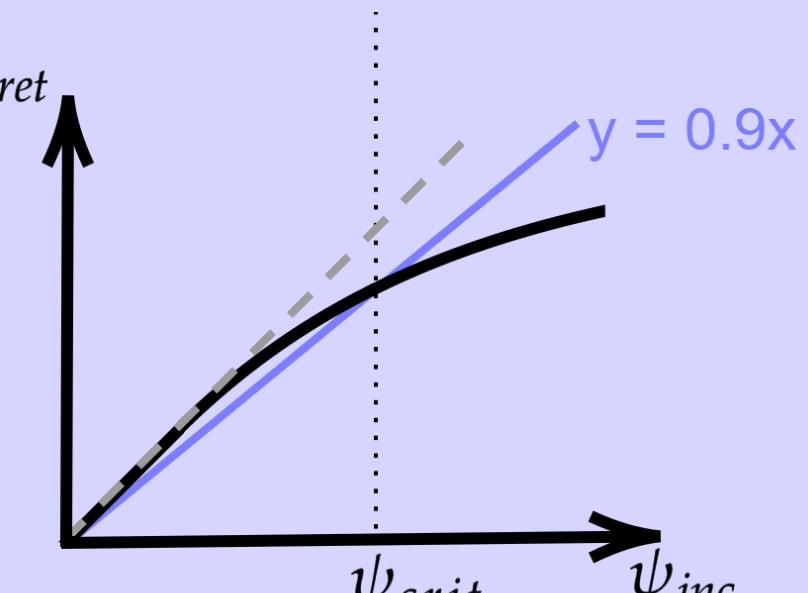
- For radionuclide collections the goal is to
 - maximize the amount of collected radioisotopes
- Self-sputtering has limited several collections at CERN-MEDICIS
- Aim: investigate self-sputtering during radionuclide collections

General principle



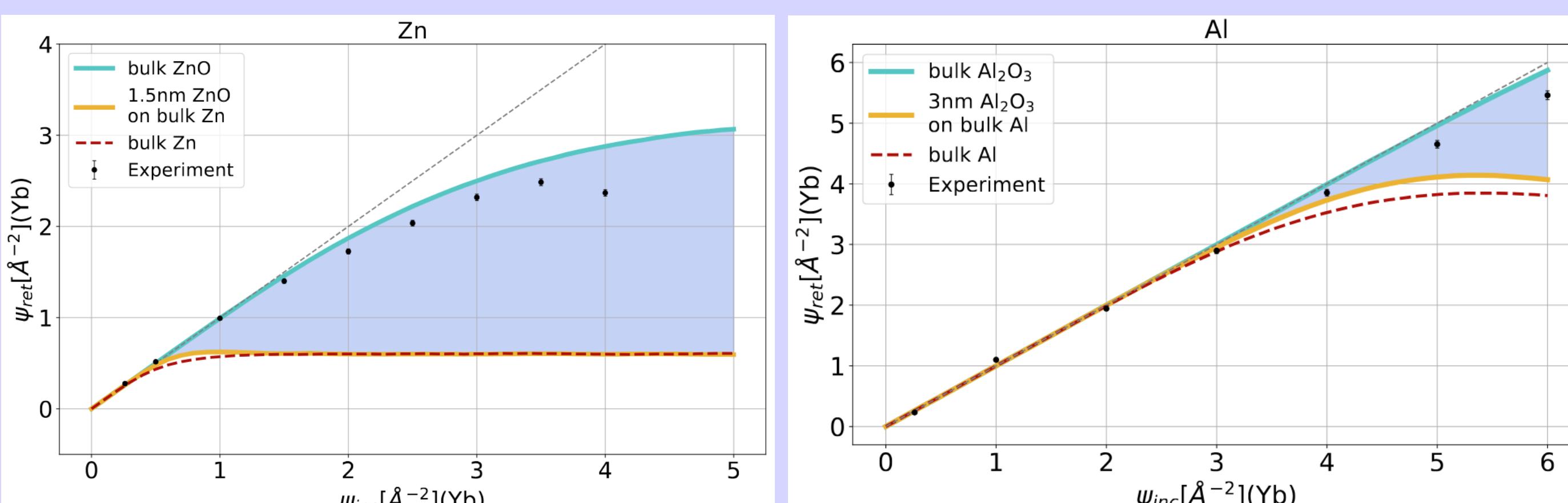
TRIDYN

- Monte Carlo based simulation package [1, 2]
- Dynamic** changes to the target \leftrightarrow SRIM [3]
- Self sputtering limit: $\psi_{crit}: \psi_{ret} < 0.9\psi_{inc}$



Validation of TRIDYN simulations

- Implantation of Yb in Zn and Al foils
- In between implantations: foils subject to air \rightarrow Native layer of oxygen forms on surface
- Expectation within pure Zn/Al with native oxide layer simulation and ZnO/Al₂O₃ simulation



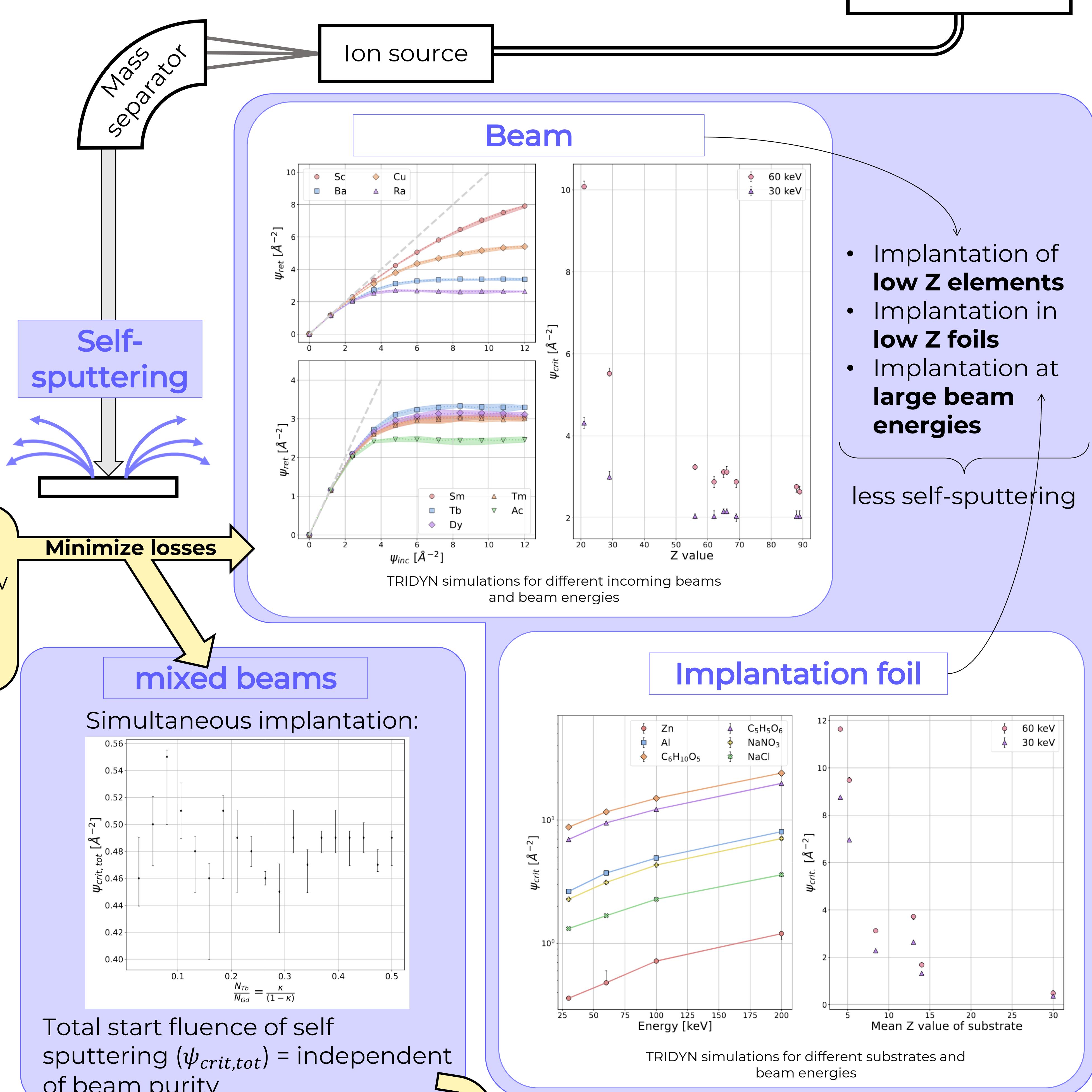
- Test for K implantation in Au and C \rightarrow TRIDYN did not work well, likely due to immiscibility of the compounds

Conclusion and outlook

- Experimental confirmation** of TRIDYN simulations
- Self-sputtering is optimized by **minimizing the Z of the foil and beam, maximizing the energy of the beam** and maximizing the implantation area
- Total fluence** can be used as indication for when self-sputtering starts to become significant

References

- Tridyn application examples - helmholtz-zentrum dresden-rossendorf, HZDR. <https://www.hzdr.de/db/Cms?pNid=0&pOid=65033>.
- W. Möller and W. Eckstein—TRIM simulation code including dynamic composition changes. *Nuclear Instruments and Methods in Physics Research Section B: Beam Interactions with Materials and Atoms*, 2(1-3):814–818, 1984. doi:10.1016/0168-583X(84)90321-5.
- R. Stadlmayr, P.S. Szabo, D. Mayer, C. Cupak, T. Dittmar, L. Bischoff, S. M'oller, M. Rasi'nski, R.A. Wilhelm, W. M'oller, et al. Sputtering of nanostructured tungsten and comparison to modelling with TRIDYN. *Journal of Nuclear Materials*, 532:152019, 2020. doi:10.1016/j.jnucmat.2020.152019.
- R. Heinke, E. Chevallay, K. Chrysaliidis, T. E. Cocolios, C. Duchemin, V. N. Fedossev, S. Hurier, L. Lambert, B. Leenders, B. A. Marsh, et al. Efficient production of high specific activity thulium-167 at Paul Scherrer Institute and CERN-MEDICIS. *Frontiers in medicine* 8 (2021) 712374. doi:10.3389/fmed.2021.712374



Back-of-the-envelope calculation framework

- Critical fluence of a **pure beam** ($\psi_{crit,tot}^{pure X}$) = good estimate for **total incoming critical fluence** ($\psi_{crit,tot}$, including all contaminants) at which **sputtering of the nuclide of interest** starts:

$$\psi_{crit,tot} \approx \psi_{crit,tot}^{pure X}$$
- Translated to experimentally accessible quantities:
 - Critical activity** of isotope of interest:

$$A_{crit} = (2\pi\sigma_r^2)\kappa\lambda\psi_{tot,crit} \approx (2\pi\sigma_r^2)\kappa\lambda\psi_{tot,crit}^{pure X}$$
 - Total (isotope of interest + contaminants) **integrated charge** on the foil:

$$Q_{crit}^{int} \approx (2\pi\sigma_r^2)q\psi_{tot,crit}^{pure X}$$

Example

- 2020 ¹⁶⁷Tm collections [4]: 60keV implantation in Zn foil
- Expect self-sputtering effects at an implanted activity of:

$$A_{crit} \approx 2\pi\sigma_r^2\lambda\psi_{tot,crit}^{pure X}\kappa = 2\pi(9 \cdot 10^6 A)^2 0.095 \frac{1}{days} 0.480 \frac{1}{A^2} 0.004 = 0.845 \text{ MBq}$$
- But implantation was continued until $\sim 5 \text{ MBq}$ \odot
 - Self-sputtering effects were clearly seen
 - Half of implanted activity was 'lost'
 - Au foil is visible through Zn coating because of sputtered Zn

